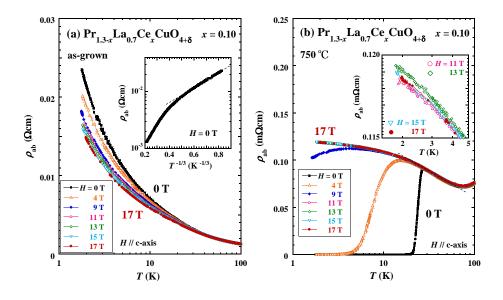
In-Plane Electrical Resistivity in Magnetic Fields and Electronic/Spin States in Pr_{1.3-x}La_{0.7}Ce_xCuO_{4+δ} High-T_c Superconductor with the T' Structure T'型銅酸化物高温超伝導体 Pr_{1.3-x}La_{0.7}Ce_xCuO_{4+δ}における 磁場中面内電気抵抗率と電子・スピン状態



We have measured the ab-plane electrical resistivity in magnetic fields parallel to the c-axis for T'-Pr_{1.3-x}La_{0.7}Ce_xCuO_{4+ δ} (x=0.10) high- T_c superconducting single crystals with various oxygen contents. It has been found that a strongly localized state of carriers in the as-grown crystal changes to a metallic state bringing about the Kondo effect through the reduced annealing. These results can be understood in terms of a band model based on the so-called non-doped superconductivity in the parent cuprates with the T' structure. It has been concluded that the mechanism of superconductivity in the electron-doped cuprates may be different from that in the hole-doped cuprates.

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Reference: T. Adachi, Y. Mori, M. Kato, T. Nishizaki, T. Sasaki, N. Kobayashi and Y. Koike, "Evolution of electronic states through reduced annealing in electron-doped $Pr_{1.3-x}La_{0.7}Ce_xCuO_{4+\delta}$ (x=0.10) single crystals", in preparation.

様々な条件で還元処理を施した T'型銅酸化物高温超伝導体 $Pr_{1.3-x}La_{0.7}Ce_xCuO_{4+\delta}$ (x=0.10) 単結晶において,c 軸に平行な磁場中での ab 面内電気抵抗率の測定を行った. その結果,As-grown でのキャリアの強局在状態が,還元とともに近藤効果を伴う金属 状態へ変化することを見出した.この結果は,T'型銅酸化物の母物質で見られる所謂 ノンドープ超伝導に基づいたバンドモデルで解釈できる.すなわち,電子型の超伝導のメカニズムはホール型とは異なる可能性があると結論した.

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